

4.5Ω Low Voltage Dual SPDT Analog Switch

FEATURES

- High Bandwidth: 300MHz
- High Speed, Typically 30ns
- Supply Range: +1.8V to +5.5V
- Low ON-State Resistance, 4.5Ω(TYP)
- Break-Before-Make Switching
- Rail-to-Rail Operation
- TTL/CMOS Compatible
- Extended Industrial Temperature Range: -40°C to +125°C

APPLICATIONS

- Wearable Devices
- Battery-Operated Equipment
- Signal Gating, Chopping, Modulation or Demodulation (Modem)
- Portable Computing
- Cell Phones

FUNCTION TABLE

LOGIC	NO1, NO2	NC1, NC2
0	OFF	ON
1	ON	OFF

PIN DESCRIPTION

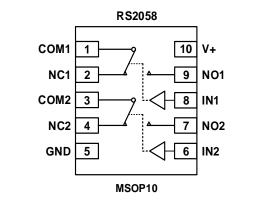
DESCRIPTION

The RS2058 is a dual, single-pole double-throw (SPDT) analog switch that is designed to operate from 1.8 V to 5.5 V.

The RS2058 device can handle both analog and digital signals. It features hign-bandwidth(300MHz) and low on-resistance (4.5Ω TYP).

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

PIN CONFIGURATIONS



NAME	PIN	FUNCTION	
COM1, COM2	1, 3	Common Terminal	
NC1, NC2	2, 4	rmally-Closed Terminal	
GND	5	Ground	
IN2, IN1	6, 8	Digital Control Pin	
NO2, NO1	7, 9	Normally-Open Terminal	
V+	10	Power Supply	

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

V+, IN to GND	0.3V to 6.0V
Analog, Digital Voltage Range ⁽²⁾	- 0.3 to (V+) + 0.3V
Continuous Current NO, NC, or COM	±300mA
Peak Current NO, NC, or COM	±500mA
Storage Temperature	. −65°C to +150°C
Operating Temperature	−40°C to +125°C
Junction Temperature	
Package Thermal Resistance @ TA = +2	25°C
SOT23-5, SOT23-6	200°C/W
MSOP-10, SOIC-8 ,TSSOP-8	150°C/W
SOIC-14, TSSOP-14	100°C/W
Lead Temperature (Soldering, 10s)	260°C
ESD Susceptibility	
НВМ	1000V
MM	100V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to 10mA or less.



ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING	PACKAGE OPTION
RS2058	RS2058XN	-40°C~125°C	MSOP10	RS2058	Tape and Reel,3000



ELECTRICAL CHARACTERISTICS

V+ = 5.0 V, T_A = -40°C to 125°C (unless otherwise noted))

PARAMETER	SYMBOL	CONDITIONS	V+	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH								
Analog Signal Range	Vno, Vnc, Vcom			FULL	0		V+	V
		V_{NO} or $V_{NC} = V + /2$,	5V	+25°C		4.5	8	Ω
On-Resistance	Ron		50	FULL			8.5	Ω
On-Resistance		I _{COM} = -10mA, Switch ON, See Figure 1	3.3V	+25°C		7	10	Ω
			3.3V	FULL			10.5	Ω
			5V	+25°C		0.15	0.3	Ω
On-Resistance Match	Р	V_{NO} or $V_{NC} = V + /2$,	50	FULL			0.4	Ω
Between Channels	Ron	I _{COM} = -10mA, Switch ON, See Figure 1	3.3V	+25°C		0.15	0.3	Ω
			3.3V	FULL			0.4	Ω
	Rflat(on)	$0 \leqslant (V_{NO} \text{ or } V_{NC}) \leqslant V \text{+/2},$ $I_{COM} = \text{-10mA},$ Switch ON, See Figure 1	5V	+25°C		2	3	Ω
On-Resistance Flatness			50	FULL			3.3	Ω
On-Resistance Flatness			3.3V	+25°C		3	4	Ω
				FULL			4.3	Ω
NC,NO OFF Leakage Current	INC(OFF), INO(OFF)	V _{NO} or V _{NC} = 0.3V, V+/2 V _{COM} = V+/2, 0.3V See Figure 2	1.8 to 5.5V	FULL			1	μA
NC,NO,COM ON Leakage Current	Inc(on), Ino(on), Icom(on)	V _{NO} or V _{NC} = 0.3V, Open V _{COM} = Open, 0.3V See Figure 2	1.8 to 5.5V	FULL			1	μA
DIGITAL CONTROL INP	UTS ⁽¹⁾		•					
	Vinh		5V	FULL	1.5			V
Input High Voltage			3.3V	FULL	1.3			V
1	Vinl		5V	FULL			0.6	V
Input Low Voltage			3.3V	FULL			0.5	V
Input Leakage Current	lin	VIN = VIO or 0	1.8 to 5.5V	FULL			1	μA

(1) All unused digital inputs of the device must be held at Vio or GND to ensure proper device operation.

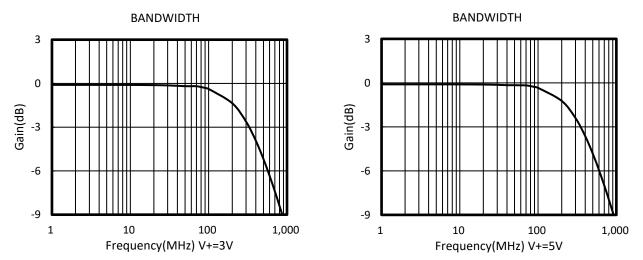


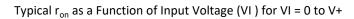
ELECTRICAL CHARACTERISTICS (continued) V+ = 5.0 V, TEMP= -40°C to 125°C (unless otherwise noted))

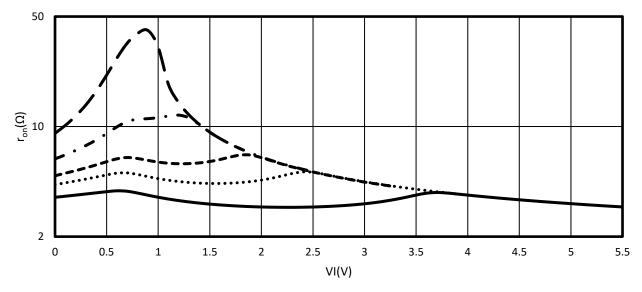
PARAMETER	SYMBOL	CONDITIONS		V+	TEMP	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS									
Turn-On Time	$V_{COM} = V+, R_L = 300\Omega, C_L = 35pF,$		5V	+25°C		30		na	
	ton	See Figure 5		3.3V	+25 C		40		ns
Turn-Off Time	torr	$V_{COM} = V_{+}, R_{L} = 300\Omega, C_{L}$	= 35pF,	5V		25		ns	
	LOFF	See Figure 5		3.3V	+25°C		30		
Break-Before-Make		$V_{NO1} = V_{NC1} = V_{NO2} = V_{NC2}$,	5V			5		ns
Time Delay	t _{ввм}	$R_L = 300\Omega, C_L = 35pF, See 6$	Figure	3.3V	+25°C		8		
Off Isolation	Oiso	R∟ = 50Ω, Switch OFF, See Figure 8	f = 10MHz		+25℃		-52		dB
			f = 1MHz		+25°C		-71		dB
-3dB Bandwidth	BW	Switch ON, R∟ = 50Ω See Figure 7			+25℃		300		MHz
NC,NO OFF Capacitance	CNC(OFF), CNO(OFF)	V _{NC} or V _{NO} =V+/2 or GND, Switch OFF See Figure 4			+25℃		5		pF
NC,NO,COM ON Capacitance	CNC(ON), CNO(ON), CCOM(ON)	V _{NC} or V _{NO} =V+/2 or GND, Switch ON See Figure 4			+25℃		15		pF
POWER REQUIREMENTS									
Power Supply Range	V+				FULL	1.8		5.5	V
Power Supply Current	I+	V_{IN} = GND or V ₊		5.5V	FULL			1	μA



TYPICAL CHARACTERISTICS







V+=5.5V ••••• V+=4V ••• V+=3.3V ••• V+=2.5V ••• V+=1.8V



Parameter Measurement Information

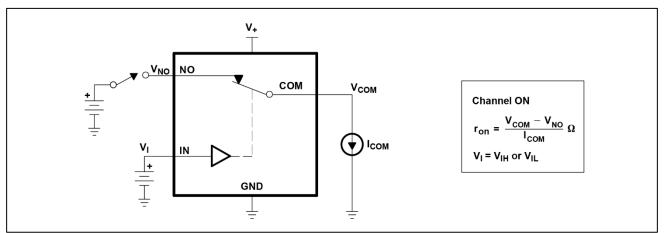


Figure 1.ON-State Resistance (ron)

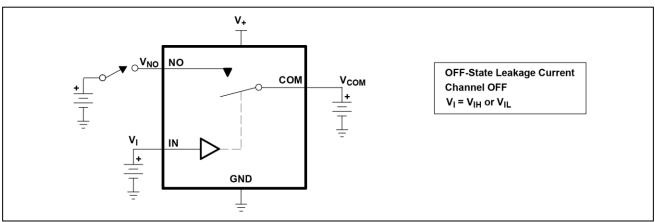


Figure 2.OFF-State Leakage Current (ICOM(OFF), INO(OFF))

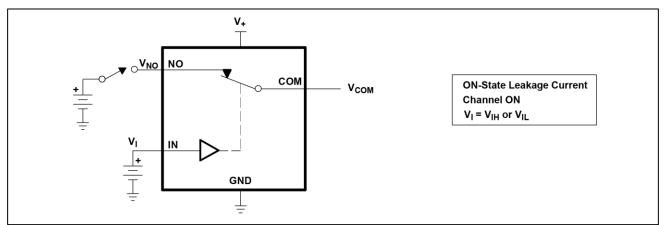
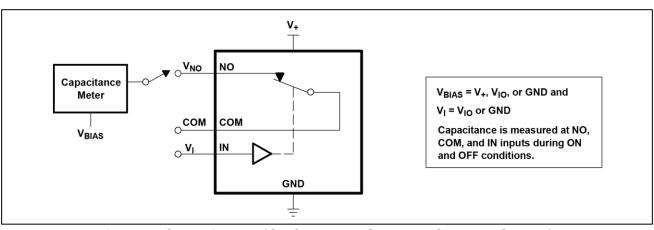
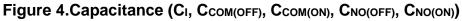


Figure 3.ON-State Leakage Current (ICOM(ON), INO(ON))







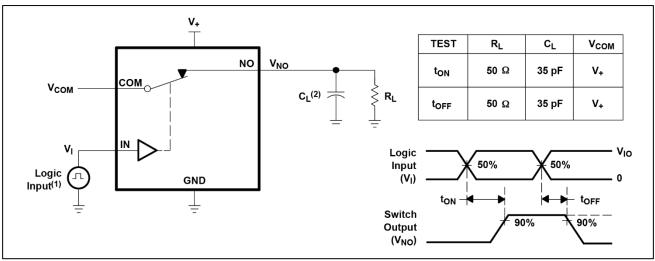


Figure 5.Turn-On (ton) and Turn-Off Time (toff)

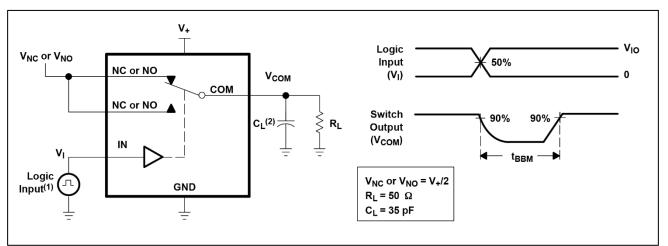


Figure 6.Break-Before-Make Time (t_{BBM})



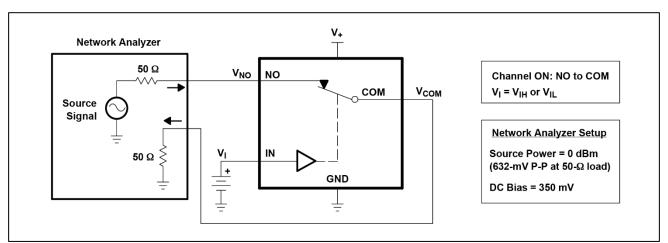


Figure 7.Bandwidth (BW)

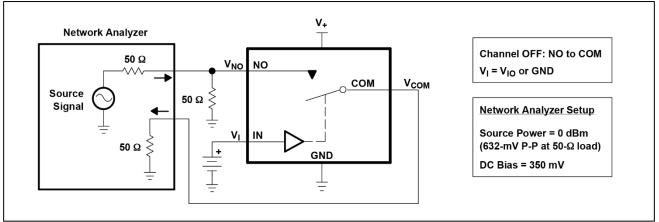


Figure 8.OFF Isolation (O_{ISO})

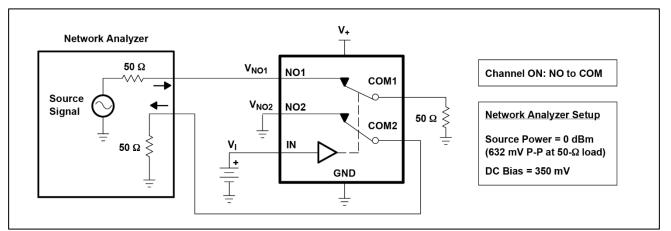


Figure 9.Crosstalk (XTALK)



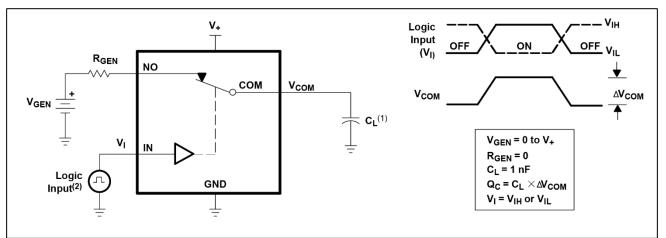


Figure 10.Charge Injection (Qc)

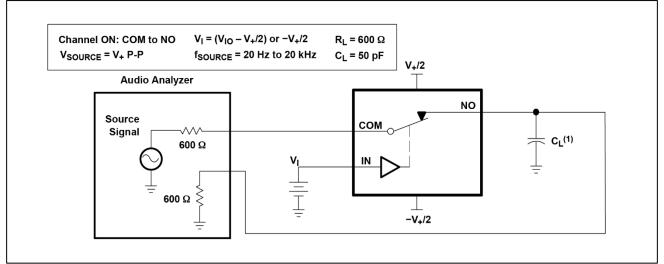
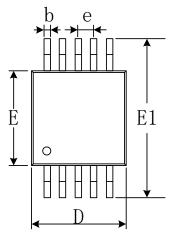
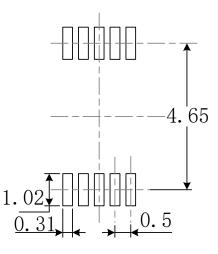


Figure11.Total Harmonic Distortion (THD)

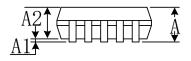


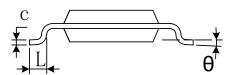
PACKAGE OUTLINE DIMENSIONS MSOP-10





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions I	n Millimeters	Dimensions In Inches			
Symbol	Min	Мах	Min	Мах		
A	0.820	1.100	0.032	0.043		
A1	0.020	0.150	0.001	0.006		
A2	0.750	0.950	0.030	0.037		
b	0.180	0.280	0.007	0.011		
с	0.090	0.230	0.004	0.009		
D	2.900	3.100	0.114	0.122		
е	0.50(BSC)	0.020(BSC)			
E	2.900	3.100	0.114	0.122		
E1	4.750	5.050	0.187	0.199		
L	0.400	0.800	0.016	0.031		
θ	0°	6°	0°	6°		

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